

描述 / Descriptions

TO-92LM 塑封封装 PNP 半导体三极管。Silicon PNP transistor in a TO-92LM Plastic Package.

特征 / Features

击穿电压高,反向传输电容小,高频特性好。

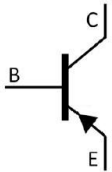
High breakdown voltage, small reverse transfer capacitance and excellent high frequency characteristic.

用途 / Applications

用于彩电行输出和高击穿电压驱动。

Color TV chroma output and high breakdown voltage driver.

内部等效电路 / Equivalent Circuit



引脚排列 / Pinning



PIN1 : Base PIN 2 : Collector PIN 3 : Emitter

放大及印章代码 / h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	C	D	E	F
h_{FE} Range	40~80	60~120	100~200	160~320

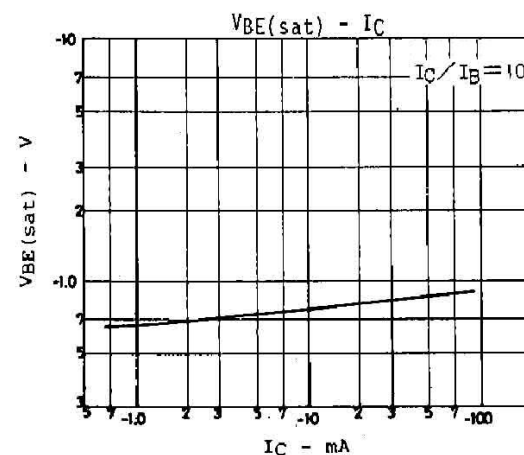
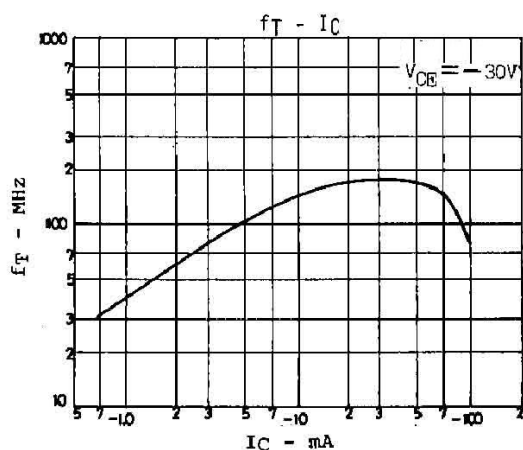
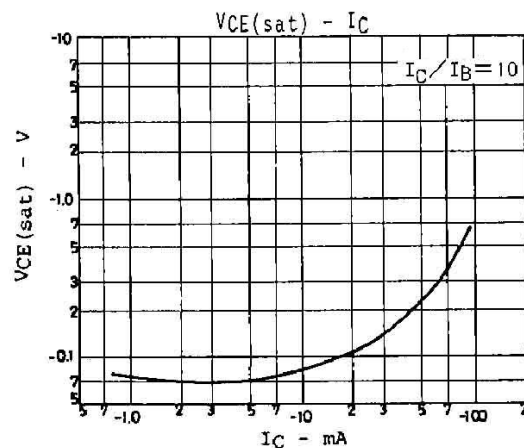
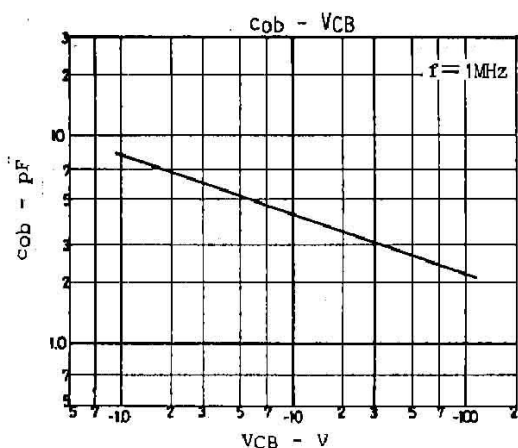
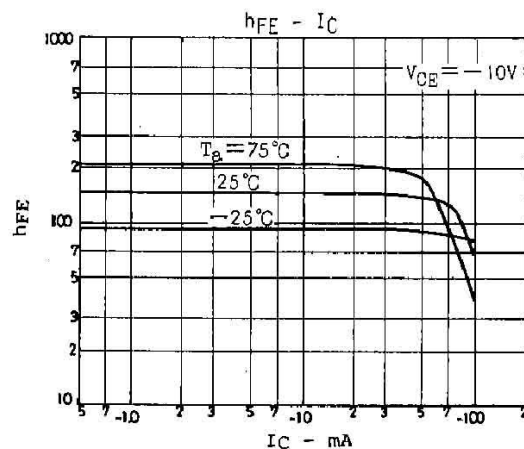
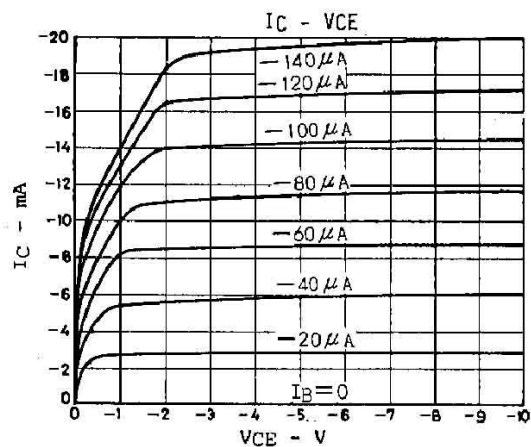
极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Collector to Base Voltage	V_{CBO}	-300	V
Collector to Emitter Voltage	V_{CEO}	-300	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-100	mA
Collector Current – Continuous(Pulse)	I_{CP}	-200	mA
Collector Power Dissipation	P_C	1.0	W
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C = -10\mu A$ $I_E = 0$	-300			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C = -1.0mA$ $R_{BE} = \infty$	-300			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E = -10\mu A$ $I_C = 0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -200V$ $I_E = 0$			-0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB} = -4.0V$ $I_C = 0$			-0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = -10V$ $I_C = -10mA$	40		320	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -20mA$ $I_B = -2.0mA$			-0.6	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -20mA$ $I_B = -2.0mA$			-1.0	V
Transition Frequency	f_T	$V_{CE} = -30V$ $I_C = -10mA$		150		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -30V$ $f = 1.0MHz$		3.1		pF
Reverse Transfer Capacitance	C_{re}	$V_{CB} = -30V$ $f = 1.0MHz$		2.3		pF

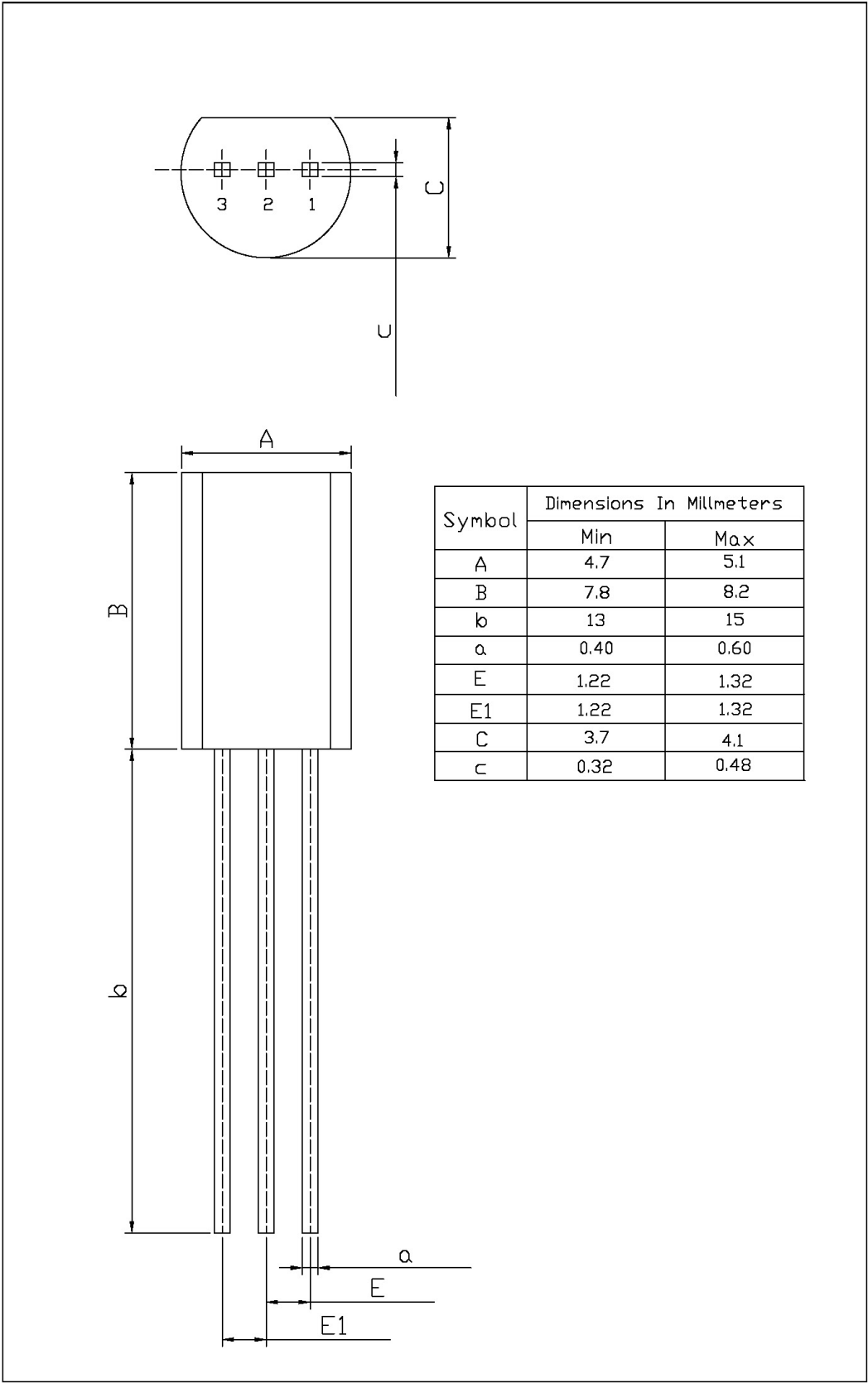
电参数曲线图 / Electrical Characteristic Curve



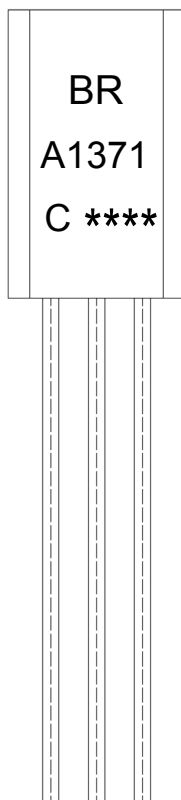
外形尺寸图 / Package Dimensions

T0-92LM

Unit: mm



印章说明 / Marking Instructions



说明：

BR: 为公司代码

A1371 : 为型号代码

C: 为 h_{FE} 分档代码

**** : 为生产批号代码，随生产批号变化。

Note:

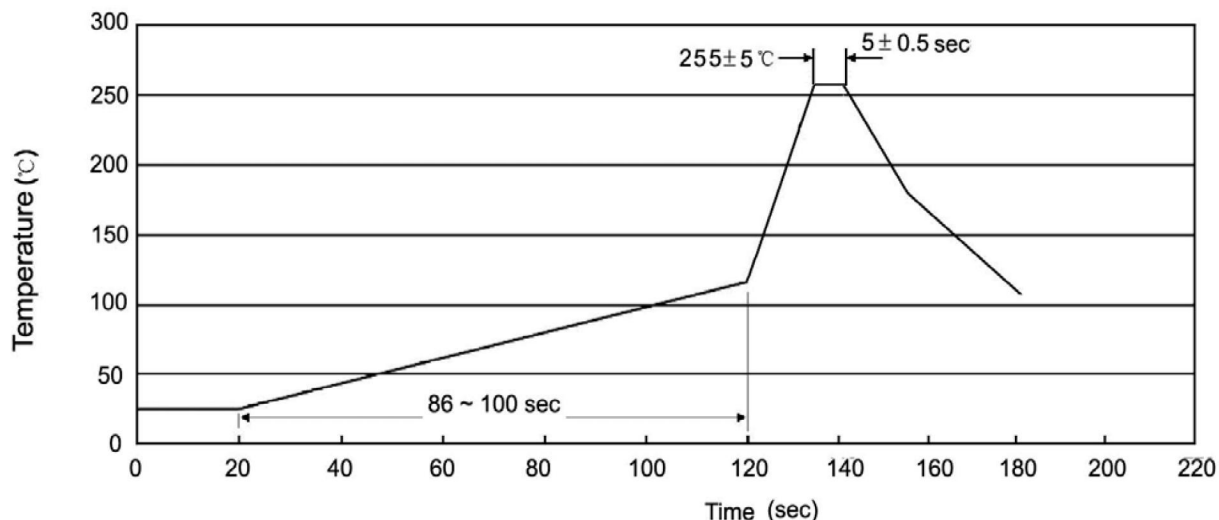
BR: Company Code.

A1371: Product Type.

C: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

波峰焊温度曲线图(无铅) / Temperature Profile for Dip Soldering(Pb-Free)



说明：

- 1、预热温度 25 ~ 150°C，时间 60 ~ 90sec;
- 2、峰值温度 255±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：270±5°C

时间：10±1 sec.

Temp.:270±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

散件包装 / BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-92LM	1,000	8	8,000	5	40,000	135×190	237×172×102	560×245×195

编带包装 / AMMO

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)	
	Units/tape 只/纸带	Tape/Inner Box 纸带/盒	Rows/Inner Box 纸带层/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Inner Box 盒	Outer Box 箱
TO-92LM	2,500	1	100	10	25,000	328×230×42	小箱 480×346×235 大箱 547×407×268

使用说明 / Notices